TOSHIBA Transistor Silicon NPN Epitaxial Type

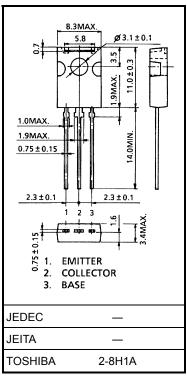
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Strobe Flash Applications Medium Power Amplifier Applications

- High DC current gain: hFE (1) = 800 to 3200 (VCE = 2 V, IC = 0.5 A) : hFE (2) = 250 (VCE = 2 V, IC = 4 A)
- Low saturation voltage: V_{CE} (sat) = 0.5 V (max) (IC = 4 A, IB = 40 mA)
- High collector power dissipation: $P_C = 10 \text{ W} (T_c = 25^{\circ}\text{C}),$ $P_C = 1.5 \text{ W} (T_a = 25^{\circ}\text{C})$

Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	50	V	
Collector-emitter voltage		V _{CES}	40	V	
		V _{CEO}	20		
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	Ι _C	5	A	
	Pulse (Note)	I _{CP}	8		
Base current		Ι _Β	0.5	А	
Collector power dissipation	Ta = 25°C	Pc	1.5	w	
	Tc = 25°C	ГC	10		
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.82 g (typ.)

Note: Pulse test: Pulse width = 10 ms (max), duty cycle = 30% (max)

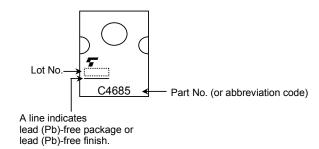
Electrical Characteristics (Tc = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 50 V, I _E = 0	—	_	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	20	_	_	V
DC current gain	h _{FE (1)}	V _{CE} = 2 V, I _C = 0.5 A	800	—	3200	
	h _{FE (2)}	V _{CE} = 2 V, I _C = 4 A	250	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 4 A, I _B = 40 mA	—	—	0.5	V
Base-emitter voltage	V _{BE}	V _{CE} = 2 V, I _C = 4 A	_	_	1.2	V
Transition frequency	f _T	V _{CE} = 2 V, I _C = 0.5 A	_	150	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	45	_	pF

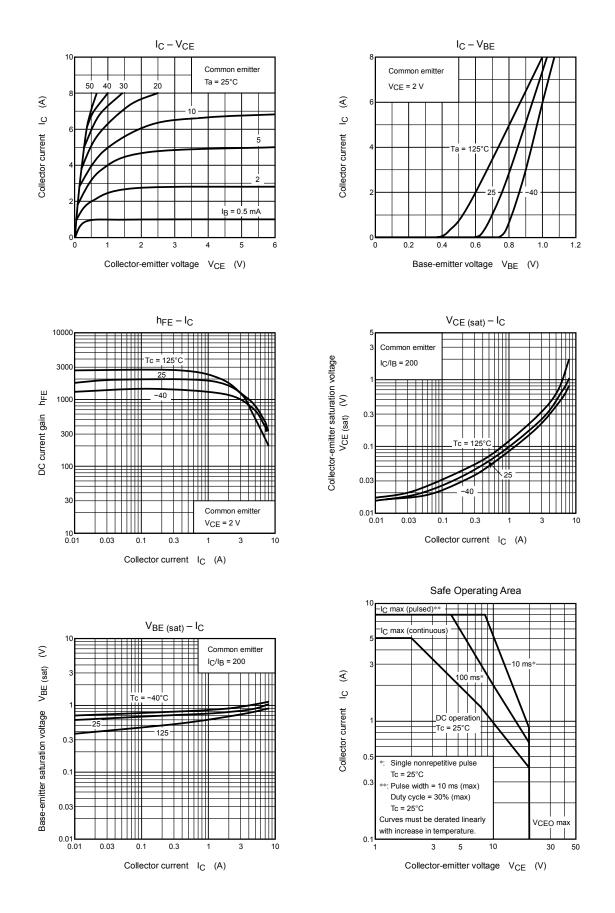
Unit: mm

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Marking



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